

High Intensity SMD LED

Color	Туре	Technology	Angle of Half Intensity
			±φ
Soft orange	TLMF310.	AllnGaP on GaAs	60°

Description

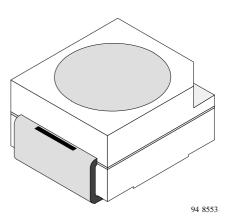
This device has been designed to meet the increasing demand for AlInGaP technology.

The package of the TLMF310. is the P–LCC–2 (equivalent to a size B tantalum capacitor).

It consists of a lead frame which is embedded in a white thermoplast. The reflector inside this package is filled up with clear epoxy.

Features

- SMD LED with exceptional brightness
- Luminous intensity categorized
- Compatible with automatic placement equipment
- EIA and ICE standard package
- Compatible with infrared, vapor phase and wave solder processes according to CECC
- Available in 8 mm tape
- Low profile package
- Non-diffused lens: excellent for coupling to light pipes and backlighting
- Low power consumption
- Luminous intensity ratio in one packaging unit $I_{Vmax}/I_{Vmin} \le 2.0$, optional ≤ 1.6



Applications

- Automotive: backlighting in dashboards and switches
- Telecommunication: indicator and backlighting in telephone and fax
- Indicator and backlight for audio and video equipment
- Indicator and backlight in office equipment
- Flat backlight for LCDs, switches and symbols
- General use

Absolute Maximum Ratings

 $T_{amb} = 25$ °C, unless otherwise specified **TLMF310...**

Parameter	Test Conditions	Symbol	Value	Unit
Reverse voltage		V _R	5	V
DC forward current	$T_{amb} \le 60^{\circ}C$	I _F	30	mA
Surge forward current	$t_p \le 10 \ \mu s$	I _{FSM}	0.1	Α
Power dissipation	$T_{amb} \le 60^{\circ}C$	P _V	80	mW
Junction temperature		T _i	125	°C
Operating temperature range		T _{amb}	-40 to +100	°C
Storage temperature range		T _{stg}	-55 to +100	°C
Soldering temperature	t ≤ 5 s	T _{sd}	260	°C
Thermal resistance junction/ambient	mounted on PC board (pad size > 16 mm ²)	R _{thJA}	400	K/W



Optical and Electrical Characteristics

 $T_{amb} = 25^{\circ}C$, unless otherwise specified

Soft orange (TLMF310.)

Parameter	Test Conditions	Туре	Symbol	Min.	Тур.	Max.	Unit
Luminous intensity 2)	$I_F = 10 \text{ mA}$	TLMF3100	I _V	25	50		mcd
		TLMF3101	I _V	40		125	mcd
Luminous intensity 1)		TLMF3102	I _V	32		100	mcd
Dominant wavelength	$I_F = 10 \text{ mA}$		λ_{d}	598	605	611	nm
Peak wavelength	$I_F = 10 \text{ mA}$		λ_{p}		610		nm
Angle of half intensity	$I_F = 10 \text{ mA}$		φ		±60		deg
Forward voltage	$I_F = 20 \text{ mA}$		V_{F}		2	2.6	V
Reverse voltage	$I_R = 10 \mu A$		V_{R}	5			V
Junction capacitance	$V_R = 0$, $f = 1$ MHz		C _i		15		pF
1) in one Packing Unit I _V M	Packing Unit I _V Min./ I _V Max. ≦ 2						

Typical Characteristics (T_{amb} = 25°C, unless otherwise specified)

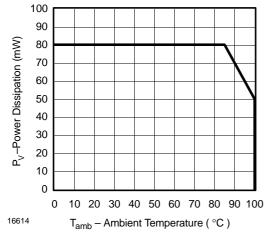


Figure 1. Power Dissipation vs. Ambient Temperature

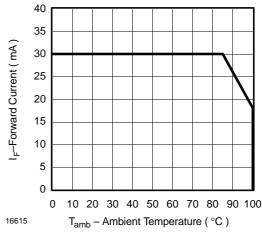


Figure 2. Forward Current vs. Ambient Temperature



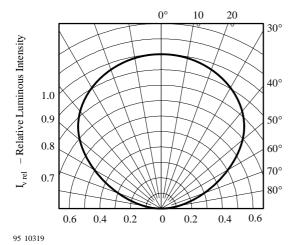


Figure 3. Rel. Luminous Intensity vs. Angular Displacement

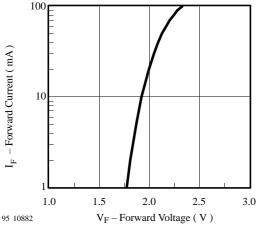


Figure 4. Forward Current vs. Forward Voltage

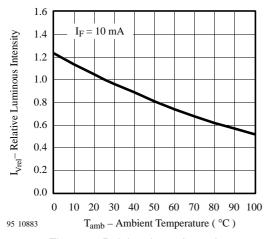


Figure 5. Rel. Luminous Intensity vs. Ambient Temperature

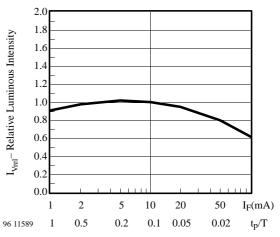


Figure 6. Rel. Lumin. Intensity vs. Forw. Current/Duty Cycle

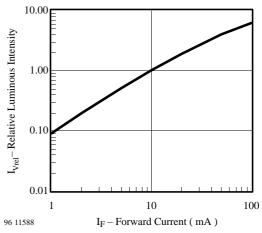


Figure 7. Relative Luminous Intensity vs. Forward Current

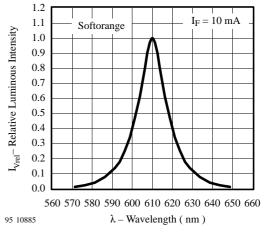


Figure 8. Relative Luminous Intensity vs. Wavelength



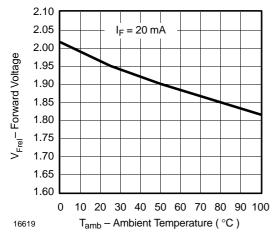


Figure 9. Forward Voltage vs. Ambient Temperature

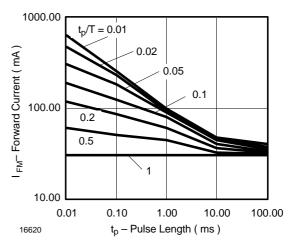
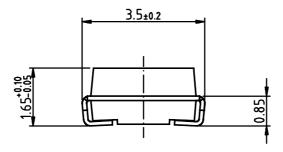
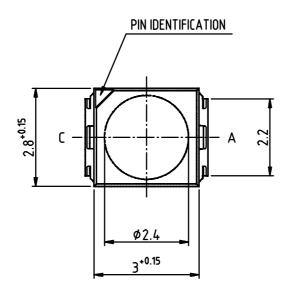


Figure 10. Forward Current vs. Pulse Length



Dimensions in mm

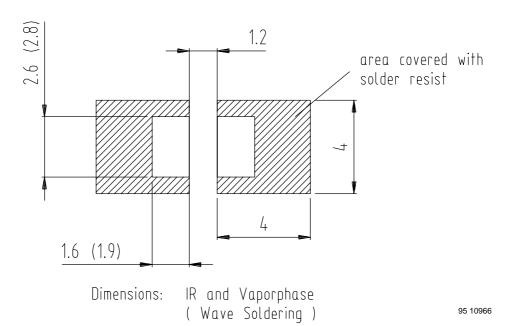






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Dimensions in mm





Ozone Depleting Substances Policy Statement

It is the policy of Vishay Semiconductor GmbH to

- 1. Meet all present and future national and international statutory requirements.
- 2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

- 1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
- Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
- 3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design and may do so without further notice. Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay Telefunken products for any unintended or unauthorized application, the buyer shall indemnify Vishay Telefunken against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

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